

April 2001 Revised August 2024

## 74LCX16543

# Low Voltage 16-Bit Registered Transceiver with 5V Tolerant Inputs and Outputs

### **General Description**

The LCX16543 contains sixteen non-inverting transceivers containing two sets of D-type registers for temporary storage of data flowing in either direction. Each byte has separate control inputs which can be shorted together for full 16-bit operation. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

The LCX16543 is designed for low voltage (2.5V or 3.3V)  $V_{CC}$  applications with capability of interfacing to a 5V signal environment.

The LCX16543 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

### **Features**

- 5V tolerant inputs and outputs
- 2.3V-3.6V V<sub>CC</sub> specifications provided
- 5.2 ns  $t_{PD}$  max ( $V_{CC} = 3.3V$ ), 20  $\mu A I_{CC}$  max
- Power down high impedance in this arturutputs
- Supports live insertion/with awa Note
- ±24 mA Output Drive ( \_\_\_\_ = ^ OV)
- Implements patente now EMI duction circulary
- Latch-up peri mance xce .s 500 inA
- ESD performan
  - Ht 90 / Model > 2000%

1ac. ne Musel > 200V

Note 1. ence the high-impedance state during power up or down,  $\overline{\text{OE}}$  rould be all to  $V_{CC}$  through a pull-up resistor; the minimum value or the runtor is determined by the curron sourcing applicity of the driver.

### Ordering Code:

Order Number	Package N nb	er Package Description
74LCX16543MEA	··^56,	-Lead Shrink Small Crutine Package (SSOP), JEDEC MO-118, 0.300 Wide
74LCX16543MTD	MTC-6	36-Lc ad Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Devices also available	Tape and Re Spe	ecify by applending the suffix letter "X" to the ordering code.
Con ectic	ւ 'agrain	Logic Symbol
THIS DE	Tras - 2 5 5 5 6 NO - 4 5 5 6 NO - 4 5 5 6 NO - 7 6 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7	-
	A <sub>B</sub> = 15 4 A <sub>9</sub> = 16 4 A <sub>10</sub> = 17 4 GND = 18 3 A <sub>11</sub> = 19 3 A <sub>12</sub> = 20 3 A <sub>13</sub> = 21 3 V <sub>CC</sub> = 22 3 A <sub>14</sub> = 23 3 A <sub>15</sub> = 24 GND = 25 3 GRA <sub>2</sub> = 26 3 IEAS <sub>2</sub> = 27 3	3 - 0, 2 - 0, 6, 0 - 0,

### **Pin Descriptions**

Pin Names	Description
OEAB <sub>n</sub>	A-to-B Output Enable Input (Active LOW)
OEBA <sub>n</sub>	B-to-A Output Enable Input (Active LOW)
CEAB <sub>n</sub>	A-to-B Enable Input (Active LOW)
CEBAn	B-to-A Enable Input (Active LOW)
LEAB <sub>n</sub>	A-to-B Latch Enable Input (Active LOW)
LEBAn	B-to-A Latch Enable Input (Active LOW)
A <sub>0</sub> -A <sub>15</sub>	A-to-B Data Inputs or B-to-A 3-STATE Outputs
B <sub>0</sub> -B <sub>15</sub>	B-to-A Data Inputs or A-to-B 3-STATE Outputs

### Data I/O Control Table

LLDA	ו וייים	Later Li	iable iliput (Active	3 LOVV)
A <sub>0</sub> -A <sub>1</sub>	5 A-to-E	B Data Inp	uts or B-to-A 3-S	TATE Outputs
B <sub>0</sub> –B <sub>15</sub>	B-to-A	A Data Inp	uts or A-to-B 3-S	TATE Outputs
able				As a
	Inputs		Latch Status	Output Polers
CEAB <sub>n</sub>	<b>LEAB</b> <sub>n</sub>	$\overline{\text{OEAB}}_{n}$	(Byte n)	(B <sub>3</sub>
Н	Х	Х	Latched	igh.
Χ	Н	Х	Latche	AL AL
L	L	Х	Trai ,c ~	JOP i
Χ	X	Н	-	'righ Z
L	X	L		Driving
			MD	IR COMP
ontrol is e	same xce,	ısing CEB/	$\overline{\Lambda}_{\rm n}, \overline{\rm LEBA}_{\rm n}$ and $\overline{\rm OEBA}_{\rm n}$	n, cok.
ptio		CON		IM
en n -in	verting tra	insceive s	makes the A-	-to-B latches transparent: a subsequent LOW-

H = HIGH Voltage Level

### Functional Description

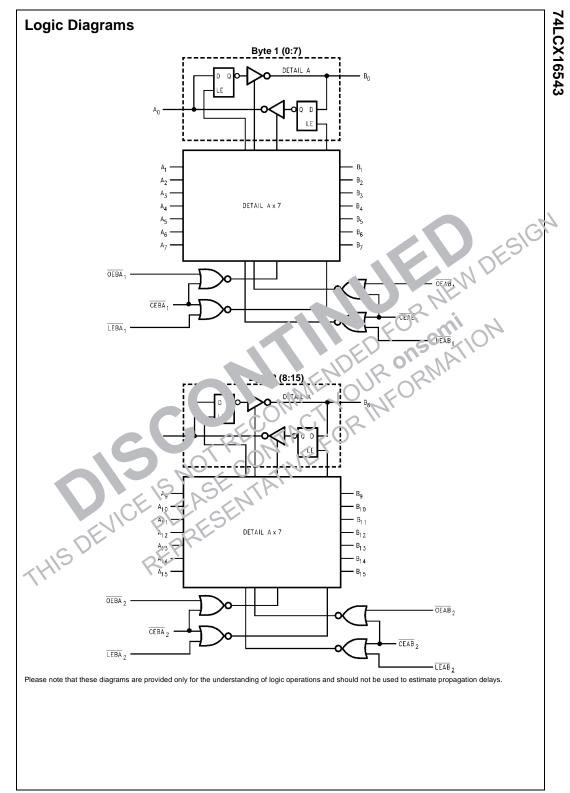
The LCX16543 contains seen in -inverting transceive s with 3-STATE or juts. The is byte controlled with each byte for tic in tically, but independent or the other. The co. of pins r y be shorted together to obtain. full out era on, the following description applies to eac. byte. I r c...a flow from A to B, for example, the A-to-L Fnah ( $\overline{CEAE}$ ) input must be LOW in order to enter da. from A A<sub>1</sub> A<sub>1</sub> or take oata from B<sub>C</sub>-B<sub>15</sub>, as indicated in the Data I/O Cont of Table With  $\overline{CEAB}_n$  LOW, a LOW signar on the A-to-B Lawh Enable ( $\overline{\text{LEAB}}_n$ ) input

makes the A-to-B latches transparent; a subsequent LOWto-H $^{\prime}$ GH transition of the  $\overline{\text{LEAB}}_{n}$  signal puts the A latches in 'ne storage mode and their outputs no longer change with the A inputs. With CEAB<sub>n</sub> and OEAB<sub>n</sub> both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the  $\overline{CEBA}_n$ ,  $\overline{LEBA}_n$  and OEBA<sub>n</sub> inputs.

L = LOW Voltage Level

X = Immaterial

A-to-B data flow shown; B-to-A flow control is e same



# Absolute Maximum Ratings(Note 2)

Symbol	Parameter	Value	Conditions	Units	
V <sub>CC</sub>	Supply Voltage	-0.5 to +7.0		V	
VI	DC Input Voltage	-0.5 to +7.0		V	
V <sub>O</sub>	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V	
		$-0.5$ to $V_{CC} + 0.5$	Output in HIGH or LOW State (Note 3)	, v	
I <sub>IK</sub>	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA	
I <sub>OK</sub>	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA	
		+50	V <sub>O</sub> > V <sub>CC</sub>	IIIA	
I <sub>O</sub>	DC Output Source/Sink Current	±50		mA	
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100		mA	
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100		mA	
T <sub>STG</sub>	Storage Temperature	-65 to +150		°C	

# **Recommended Operating Conditions** (Note 4)

Symbol	Parameter	M.	Max	Units
V <sub>CC</sub>	Supply Voltage	50	3.6	V
	. ta Re ntio.	1.5	3.6	V
V <sub>I</sub>	Input Voltage	67	5.5	V
V <sub>O</sub>	Output Voltage 'G or Low State	0	V <sub>CC</sub>	V
	3-STATE	6	5.5	V
I <sub>OH</sub> /I <sub>OL</sub>	Output Current $ \sqrt{_{CC}} = 3.0 \text{ / } - 3.6 \text{V} $ $ \sqrt{_{CC}} = 2.7 \text{V} - 2.7 \text{ / } $	50 1	+24	
	$V_{Ci} = 2.7V - 7.7V$	" nD	±12	mA
	$V_{CC} = 2.3V - 2.7V$	2 MII.	±8	
T <sub>A</sub>	Free-Air Operating Tempe was	-40	85	°C
Δt/ΔV	Input Edge Rate, V <sub>IN</sub> = 0 V–2.0V V <sub>CC</sub> = 3.0V	0	10	ns/V

Note 2: The Absolute Maximum F ings are in vall beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric v ies defined in which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric v ies defined in which life acteristics ables are not quaranteed at the Absolute Maximum Ratings. The "Recommended Operating Cond" in the will delight the conditions for actual device operation.

Note 3: Io Absolute I ximum Ratin. In electrical characteristics ables are not quaranteed at the Absolute Maximum Ratings. The "Recommended Operating Cond" in the conditions for actual device operation.

Note 4: Unused outs will be held filled or LOW. They may not float.

# Dr Ele tr. ai Characteristics

Symbo	Farameter	Conditions	V <sub>CC</sub>	T <sub>A</sub> = -40°C	to +85°C	Units	
Symbol	Parameter	Conditions	(V)	Min	Max	Ulits	
V <sub>IH</sub>	HIGH Level Input Voltage		2.3 – 2.7	1.7		V	
			2.7 – 3.6	2.0		V	
41/	LOW Level Input voltage		2.3 – 2.7		0.7	V	
	4		2.7 – 3.6		0.8	٧	
/он	HIGH Level Output Voltage	$I_{OH} = -100 \ \mu A$	2.3 – 3.6	V <sub>CC</sub> - 0.2			
		$I_{OH} = -8 \text{ mA}$	2.3	1.8			
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V	
		$I_{OH} = -18 \text{ mA}$	3.0	2.4			
		$I_{OH} = -24 \text{ mA}$	3.0	2.2			
OL.	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.3 – 3.6		0.2		
		I <sub>OL</sub> = 8 mA	2.3		0.6		
		I <sub>OL</sub> = 12 mA	2.7		0.4	V	
		I <sub>OL</sub> = 16 mA	3.0		0.4		
		I <sub>OL</sub> = 24 mA	3.0		0.55		
	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 – 3.6		±5.0	μΑ	
OZ	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$	2.3 – 3.6		±5.0		
		$V_I = V_{IH}$ or $V_{IL}$	2.3 - 3.0		±3.0	μА	
OFF	Power-Off Leakage Current	V <sub>I</sub> or V <sub>O</sub> = 5.5V	0		10	μΑ	

# DC Electrical Characteristics (Continued)

	Symbol	Parameter	Conditions	V <sub>CC</sub>	$T_A = -40^{\circ}$	C to +85°C	Units
Symbol		i didilicici	Conditions		Min	Max	Onico
	I <sub>CC</sub>	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	μА
			$3.6V \le V_1, V_0 \le 5.5V \text{ (Note 5)}$	2.3 – 3.6		±20	μΑ
	$\Delta I_{CC}$	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μΑ

Note 5: Outputs in disabled or 3-STATE only.

# **AC Electrical Characteristics**

		$T_A = -40$ °C to $+85$ °C, $R_L = 500 \Omega$						
Symbol	Parameter	V <sub>CC</sub> = 3.	3V ± 0.3V	V <sub>CC</sub> = 2.7V		$\rm V_{CC}=2.5V\pm0.2V$		
Зуппон	Farameter	C <sub>L</sub> = 50 pF		C <sub>L</sub> = 50 pF		C <sub>L</sub> = 30 pF		Units
		Min	Max	Min	Max	Min	Max	
t <sub>PHL</sub>	Propagation Delay	1.5	5.2	1.5	6.0	1.5	2	n/ C
t <sub>PLH</sub>	$A_n$ to $B_n$ or $B_n$ to $A_n$	1.5	5.2	1.5	6.0	1.5	<u>}</u>	lis
t <sub>PHL</sub>	Propagation Delay	1.5	6.5	1.5	7.5		7.8	ns
t <sub>PLH</sub>	$\overline{LEBA}_{n}$ to $A_{n}$ or $\overline{LEAB}_{n}$ to $B_{n}$	1.5	6.5	1.5	7	1.5	7.3	IIS
t <sub>PZL</sub>	Output Enable Time						1/1/4	
$t_{PZH}$	$\overline{OEBA}_n$ or $\overline{OEAB}_n$ to $A_n$ or $B_n$	1.5	6.5	1.5	7.0	1.5	8.5	ns
	$\overline{\text{CEBA}}_n$ or $\overline{\text{CEAB}}_n$ to $A_n$ or $B_n$	1.5	6.5	- 5		1.5	8.5	
t <sub>PLZ</sub>	Output Disable Time						10	
$t_{PHZ}$	OEBA <sub>n</sub> or OEAB <sub>n</sub> to A <sub>n</sub> or B <sub>n</sub>	1.5	5	1.	7.0	1.5	7.8	ns
	$\overline{\text{CEBA}}_n$ or $\overline{\text{CEAB}}_n$ to $A_n$ or $B_n$	1.5	6.	1.5	7.0	, C.S.	7.8	
t <sub>S</sub>	Setup Time, HIGH or LOW,	25		2.5		3.0		ns
	Data to LEXX <sub>n</sub>			SAL	. 18	-01/		115
t <sub>H</sub>	Hold Time, HIGH or LOW,	1.5	10	1.5	70	2.0		ns
	Data to LEXX <sub>n</sub>			" \	I'. NY			115
t <sub>W</sub>	Pulse Width, Latch Enah	3.0	10,	3.0	2 //	3.5		ns
toshl	Output to Output Skew ote 6)		1.0	٧. ١				ns
toslh		. QV	1.0					115

Note 6: Skew is defin ' as value of the diffe ence between 'he actual pronagation delay for any two separate outputs of the same device. The specification applies to volutions with volutions of the same device. The specification applies to volutions with volutions of the same device. The specification applies to volutions with volutions of the same device. The specification applies to volutions with volutions of the same device. The specification applies to volutions with volutions and volutions of the same device. The specification applies to volutions with volutions and volutions of the same device. The specification applies to volutions with volutions are specification applies to volutions.

# Dyna nic & vi shing Characteristics

Symbol	(Paramote)	Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C	Units
V <sub>OLP</sub>	Quiet Cutput Dynamic Peak Vol.	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
,C	SEY.	$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	0.6	V
V <sub>OLY</sub>	Quiet Output Dynamic Valley V <sub>OL</sub>	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
11.	•	$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	-0.6	V

# Capacitance

Symbol	Parameter	Conditions	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC}$ = Open, $V_I$ = 0V or $V_{CC}$	7	pF
C <sub>I/O</sub>	Input/Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC} = 3.3V$ , $V_{I} = 0V$ or $V_{CC}$ , $f = 10$ MHz	20	pF

### AC LOADING and WAVEFORMS Generic for LCX Family

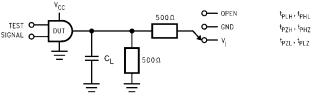
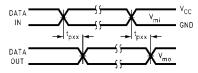
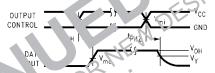


FIGURE 1. AC Test Circuit ( $C_L$  includes probe and jig capacitance)

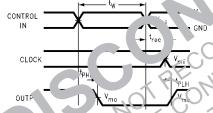
Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	6V at $V_{CC}$ = 3.3 $\pm$ 0.3V $V_{CC}$ x 2 at $V_{CC}$ = 2.5 $\pm$ 0.2V
$t_{PZH}, t_{PHZ}$	GND



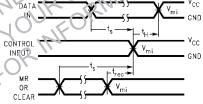
Waveform for Inverting and Non-Inverting Functions



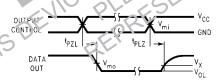
STATE Output High Trable and Disable Times for Logic



P paga. n L 'ay. Puls : Width and tree Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

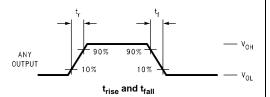
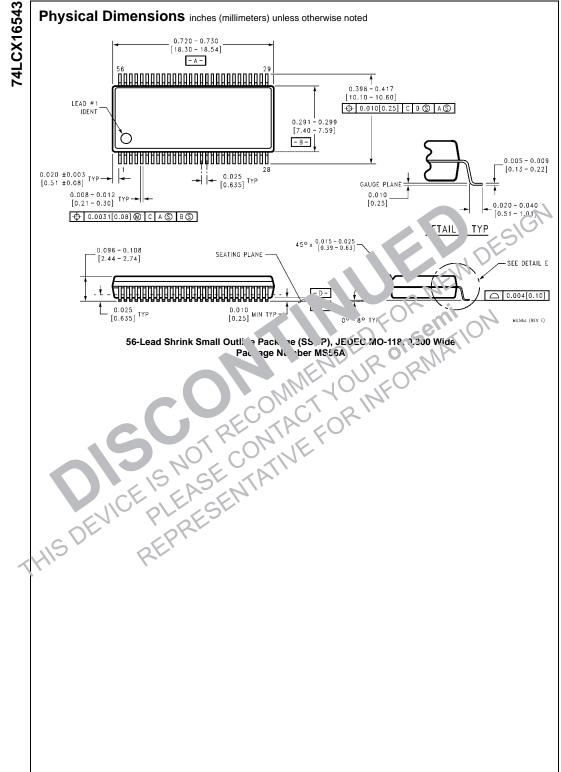
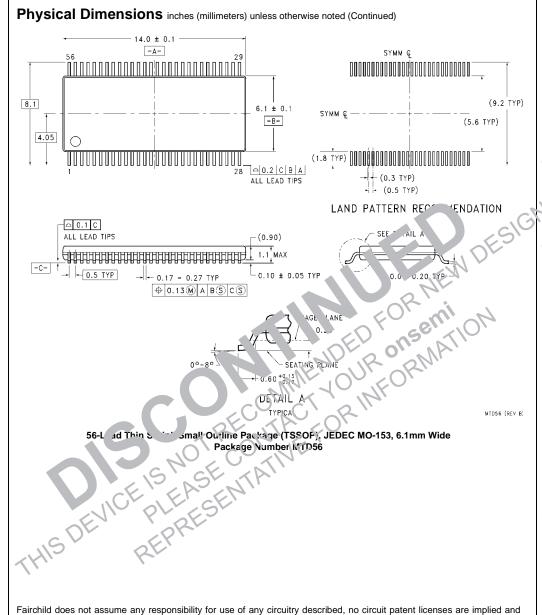


FIGURE 2. Waveforms (Input Characteristics; f =1MHz,  $t_r = t_f = 3ns$ )

Symbol	V <sub>cc</sub>					
Cymber	$3.3V \pm 0.3V$	2.7V	2.5V ± 0.2V			
V <sub>mi</sub>	1.5V	1.5V	V <sub>CC</sub> /2			
V <sub>mo</sub>	1.5V	1.5V	V <sub>CC</sub> /2			
V <sub>x</sub>	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.15V			
V <sub>y</sub>	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> – 0.15V			





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